

Experimental Evidence of Stable $2H$ Phase on the Surface of Layered $1T'$ -TaTe₂

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Abstract

We report on the low-energy electronic structure of Tantalum ditelluride ($1T'$ -TaTe₂), one of the charge density wave (CDW) materials from the group V transition metal dichalcogenides using angle-resolved photoemission spectroscopy (ARPES) and density functional theory (DFT). We find that the Fermi surface topology of TaTe₂ is quite complicated compared to its isovalent compounds such as TaS₂, TaSe₂, and isostructural compound NbTe₂. Most importantly, we discover that the surface electronic structure of $1T'$ -TaTe₂ has more resemblance to the $2H$ -TaTe₂, while the bulk electronic structure has more resemblance to the hypothetical $1T$ -TaTe₂. These experimental observations are thoroughly compared with our DFT calculations performed on $1T$ -, $2H$ - and $2H$ (monolayer)/ $1T$ -TaTe₂. We further notice that the Fermi surface topology is temperature independent up to 180 K, confirming that the $2H$ phase on the surface is stable up to 180 K and the CDW order is not due to the Fermi surface nesting.

Introduction

Investigation of the transition metal dichalcogenides (TMDCs) is quite fascinating as these systems host a wide variety of structural, physical, and electronic properties.¹⁻⁴ Particularly, the structural polymorphism in TMDCs ($1T$, $2H$, and $3R$ phases) play a significant role for their exotic physical properties such as charge density wave (CDW),^{5,6} superconductivity,⁷ magnetic ordering,⁸ topological properties,⁹ and the valleytronics¹⁰ by tuning the electronic band structure. Therefore, a thorough knowledge on the electronic band structure of TMDCs is vital for understanding their diverse electronic and physical properties.

TMDCs are in general formed by one transition metal atom (group IV, V, VI, VII, IX, and X) and two chalcogen atoms (S, Se, and Te) with the chemical formula of MX₂ (M=transition metal and X=chalcogen). Among these, the group V TMDCs, NbX₂ and TaX₂ are most attractive as they show interplay between the charge ordering (CDW) and

the superconductivity both in the $1T$ and $2H$ phases.¹¹ The mechanism of charge ordering and the superconductivity in TMDCs are under debate. Fermi surface nesting,¹² electron-phonon coupling,¹³ and the van Hove singularities¹⁴ have been proposed as the origin of CDW ordering in these systems.¹⁵ Though, the electronic properties are almost similar in both NbX_2 and TaX_2 , their structural properties are rather different. That means, at room temperature, the bulk Ta(Nb)S_2 and Ta(Nb)Se_2 can be formed in the $1T$ and $2H$ phases with octahedral and trigonal prismatic coordination in the hexagonal crystal symmetry⁴ having $(\sqrt{13} \times \sqrt{13})$ superstructure on the surface,¹⁶ while the bulk TaTe_2 and NbTe_2 are in the distorted octahedral coordination with the monoclinic crystal symmetry ($1T'$ phase) having (1×3) superstructure on the surface.¹⁷ Also at low temperatures, the surface of Ta(Nb)Te_2 goes into the (3×3) superstructure with $1T'$ phase intact.^{18–20} Further, TaTe_2 shows incommensurate CDW phase below $T_{CDW} \approx 170K$,^{13,18,19,21} whereas NbTe_2 shows commensurate CDW order at room temperature but then turns into incommensurate CDW phase just above the room temperature.^{22,23}

So far TaTe_2 and NbTe_2 are experimentally studied for their structural,^{5,13,17,24} physical properties,^{18,20} magnetic properties,²⁵ and potential applications in the energy storage materials.^{26–28} Further, unlike TaTe_2 which does not show superconductivity down to lowest possible temperature, NbTe_2 shows superconductivity below $\approx 0.5K$.²⁹ Several theoretical calculations were performed to understand their structural transition and origin of CDW in these systems by studying the electronic band structure using the DFT calculations.^{13,16,20} However, till date, one experimental ARPES report available on NbTe_2 ²² and none on TaTe_2 . One quantum oscillation study discussing the speculative band structure of TaTe_2 is available.²⁵ Since ARPES studies are utmost needed to unambiguously understand the low-energy electronic structure of these systems, we performed ultra-high resolution ARPES studies on TaTe_2 to understand the origin of CDW transition and to examine whether it is a Dirac semimetal as speculated by the quantum oscillations.²⁵

In this study, we report on the low-energy electronic structure of $1T'$ - TaTe_2 using high-

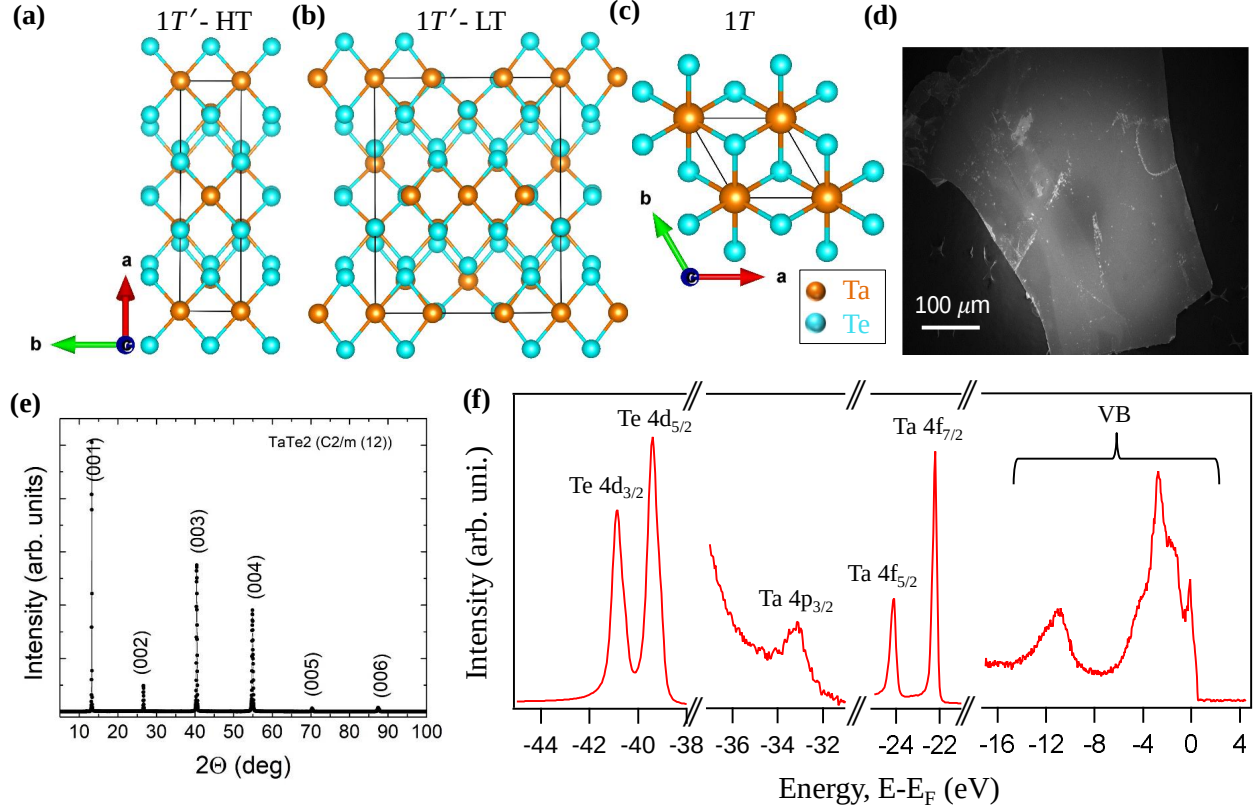


Figure 1: Distorted 1T phase (1T') or the monoclinic crystal structure of TaTe₂ at high temperature (a) and at low temperature (b). (c) Hypothetical 1T phase crystal structure of TaTe₂ projected onto the *ab*-plane. (d) Scanning electron microscope image of the 1T'-TaTe₂ single crystal. (e) X-ray diffractogram of 1T'-TaTe₂ single crystal. (f) X-ray photoemission spectra (XPS) measured with a photon energy of 100 eV. On the XPS, all core levels are identified either to Ta or Te atom.

resolution angle-resolved photoemission spectroscopy (ARPES) and density functional theory calculations. We observe that the Fermi surface of $1T'$ -TaTe₂ is in the hexagonal symmetry, which is in contradiction to its monoclinic crystal structure. We observe a totally different electronic structure of TaTe₂ when compared with the isostructural compound NbTe₂. Further, despite being in the hexagonal symmetry the Fermi surface topology of TaTe₂ is quite different when compared to the isovalent compounds, TaSe₂ and TaS₂. To fully understand the experimentally obtained electronic band structure of TaTe₂, we disentangled the surface states from bulk with the help of the slab calculations. Thus, we realize that the surface states resemble the $2H$ phase electronic structure, while the bulk states replicate the $1T$ phase electronic structure of TaTe₂. This is an interesting discovery as TaTe₂ does exist neither in $1T$ phase nor in $2H$ phase as per the observation of crystal structure. We further notice that the $1T$ phase electronic structure shows substantial band dispersion in the k_z direction. We realize that the band structure of TaTe₂ is temperature independent above and below the CDW transition temperature.

Methods

Single Crystal Growth

Single crystals of TaTe₂ were grown by chemical vapor transport method using iodine as transporting agent. The sample preparation and storage were carried out in an Ar-filled glove box where the moisture and oxygen are maintained below 0.1 ppm. Polycrystalline sample of TaTe₂, obtained by reacting stoichiometric amounts of Ta powder (Sigma Aldrich, 99.9%, metals basis) and Te (ingot, 99.99%, metals basis, Alfa Aesar) under vacuum (10^{-5} Torr) at 750° C for 48 h, was used for the single crystal growth. The polycrystalline sample was then grinded in glove box, loaded and sealed under vacuum in a quartz ampoule together with the transporting agent (iodine – 5 mg/cm³). Subsequently, the ampoule has been placed in a three-zone furnace, where a gradient temperature of 50° C has been maintained between

the source (T_1 - 870° C) and the sink zones (T_2 - 850° C) for a period of 12 days. By this procedure platelet shaped single crystals with a typical lateral dimensions of 10-15 mm were obtained.

Sample Characterization

The chemical purity and composition were confirmed using a scanning electron microscope (ZEISS Gemini SEM 500) equipped with an energy dispersive X-ray spectroscopy (EDX) probe. The phase purity of the single crystal was checked using X-ray diffraction (Bruker D8 diffractometer, Cu $K\alpha$ radiation) measurements.

ARPES measurements

ARPES measurements were carried out at 1³-ARPES end station using UE112-PGM2b beamline equipped with a Scienta R4000 analyzer having angular resolution better than 0.2° located in BESSY II (Helmholtz zentrum Berlin) synchrotron radiation center.^{30,31} Photon energies for the measurements were varied between 50 to 100 eV. The energy resolution was set between 5 and 15 meV depending on the excitation energy. Data were recorded at a chamber vacuum better than 1×10^{-10} mbar. Sample was cleaved *in situ* before the measurements. The sample temperature was kept at 1 K during the measurements. Temperature dependent ARPES data were recorded at the SIS beamline located in Swiss Light Source³² equipped with a Scienta R4000 electron analyzer with an angular resolution of better than 0.2°. The energy resolution was set at 10 meV. The sample was cleaved *in situ* before performing the measurements. The base pressure was better than 1×10^{-10} mbar during the measurements.

Theoretical Calculations

Our first-principles electronic structure calculations are performed within the framework of density functional theory (DFT) using the local density approximation (LDA)³³ of the exchange and correlation (XC) functional as implemented in the Vienna Ab-initio Simulation Package (VASP).³⁴ The projector augmented wave (PAW)³⁵ pseudo-potentials are used to describe the core electrons. Electronic wave-functions are expanded using plane waves up-to a cut-off energy of 600 eV. Periodic boundary conditions are employed and at least of 15 Å slab is used on the surface of few layers to eliminate the interaction between consecutive periodic images. The Monkhorst-Pack k-meshes are set to 11×11 (11×11×4) in the Brillouin zone for the self-consistent calculation of few layer cases (bulk), and all atoms are relaxed in each optimization cycle until atomic forces on each atom are smaller than 0.01 eV/Å. Spectral function is calculated using the QuantumATK package³⁶ where we use the VASP-relaxed structure, LDA XC functional, norm-conserving pseudopotentials for describing electron-core interactions, and SG15 (medium) type local orbital basis set.³⁷ The energy mesh cut-off for the real-space grid is chosen as 100 Hartree. We obtain the spectral function at an arbitrary plane at position z within the heterostructure from the retarded Green's function, $G_{k\parallel}$

$$A(E = E_F; k_x, k_y) = \frac{1}{\pi} G_{k\parallel}(E; z, z), \quad (1)$$

and $G_{k\parallel}$ is calculated as

$$G_{k\parallel}(E) = [E - H_{k\parallel} - \Sigma_{k\parallel}]^{-1} \quad (2)$$

Here $k_{\parallel}$ refers to the in-plane (k_x, k_y) k-points, $H_{k_{\parallel}}$ is the DFT hamiltonian of the slab and Σ is the self energy of the semi-infinite lead

Results and discussion

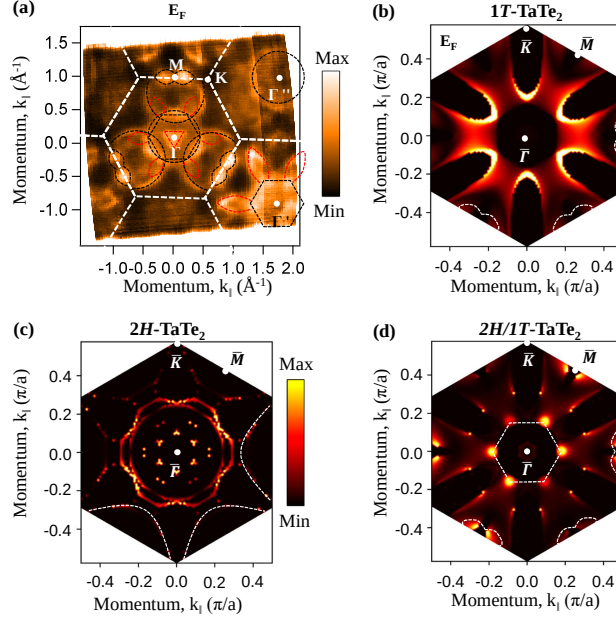


Figure 2: (a) Experimental Fermi surface map measured with a photon energy $h\nu = 100$ eV. (b), (c) and (d) Show the calculated spectral function distribution at the Fermi level plotted for semi-infinite slabs of 1T, 2H, and 2H-monolayer placed on top of the semi-infinite 1T-TaTe₂ slab, respectively.

The crystal structure of TaTe₂ in the 1T' phase with monoclinic crystal symmetry is shown in **Figure 1a** at high temperature ($T > 170$ K) and in **Figure 1b** at low temperature ($T < 170$ K) reproduced from Ref.¹⁸ As can be seen from **Figures 1a and 1b** the crystal symmetry does not change but only the lattice constants do alter above and below the CDW order transition temperature ($T \approx 170$ K). **Figure 1c** shows the hypothetical crystal structure of TaTe₂ in the 1T phase with the hexagonal crystal symmetry projected onto the *ab* plane. Scanning electron microscope (SEM) image of TaTe₂ single crystal is shown in **Figure 1d**. From the energy dispersive X-ray analysis spectroscopy (EDS) measurements (see **Figure S1** in supporting information), we derived the chemical composition as Ta_{1.06}Te₂. This suggests that there exists a 6% of excess Ta per unit cell. Such an excess amount of transition metal or chalcogen deficiency in these systems generally leads to excess electron carrier density. Otherwise, from the EDS and SEM data the sample is noticed as homogeneous. **Figure**

1e shows X-ray diffraction (XRD) pattern, measured at room temperature, indicating that TaTe₂ single crystal is crystallized in the space group of $C2/m(12)$, with lattice parameters as $a = 14.76 \text{ \AA}$, $b = 3.63 \text{ \AA}$, $c = 9.32 \text{ \AA}$, and $\beta = 110.89^\circ$. The crystal surface normal is parallel to the c -axis, analogous to the earlier reports.^{20,25} Also, we performed XPS measurements on the cleaved TaTe₂ to check the purity of the sample, before performing the ARPES measurements as shown in **Figure 1f**. All observed core levels from XPS are referred to respective binding energies of Ta and Te atoms and no other impurity peaks are detected.

Fermi surface topology of TaTe₂ in the k_x - k_y plane is shown in **Figure 2a**, measured with a photon energy of 100 eV using p -polarized light at a sample temperature of 1K and corresponding constant energy contour taken at a binding energy of 100 meV below the Fermi level is shown in **Figure 3a**. As can be seen from these maps, the Fermi pockets follow the hexagonal symmetry that is in contrast to its monoclinic crystal structure as observed from the XRD measurements (**Figure 1e**). The symmetry difference between the crystal and electronic structures could be related to the formation of bulk $(3 \times 1 \times 3)$ supercell structure as reported earlier in the case of isostructural $1T'$ -NbTe₂.²² Further, on the Fermi surface map, we could identify various Fermi pockets of circular-shaped, hexagonal-shaped, petal-shaped, half-circular-shaped, and triangular-shaped. In detail, at the Γ point we see a large circular-shaped Fermi pocket. Though we identify another large hexagonal-shaped Fermi pocket at the Γ point, due to the matrix element effects it is not very clear. But this hexagonal-shaped Fermi pocket is clearly visible as we move to the Γ' point. Further, at the Γ point we do find six petal-shaped, three half-circle-shaped and one triangular-shaped Fermi pockets. Interestingly, as we move away from Γ to the Γ' point we find a large hexagonal-shaped Fermi pocket that is not clear at the Γ point. Also, at Γ' , the size of the petal-shaped Fermi pockets is significantly enhanced compared to their size at Γ . We did not observe any half-circle-shaped Fermi pockets at Γ' . Next, at Γ'' , we could readily observe one circular-shaped Fermi pocket of the same size to the one at Γ and with a careful observation we could also find the half-circular-shaped Fermi pockets. At the M point, we observe peanut-

shaped Fermi pocket. Due to the matrix element effects out of six peanut-shaped Fermi pockets, only three are readily visible due to their high spectral intensity and the other three peanut-shaped pockets exist with reduced spectral intensity.

Since the ARPES is a surface sensitive technique, inevitably, it probes the surface electronic structure in addition to the bulk electronic structure. Therefore, it is crucial to disentangle the surface electronic structure from the bulk resulted from the surface reconstruction due to crystal cleavage under ultra-high chamber vacuum. For this purpose, we performed slab calculations of TaTe₂ in its $1T$ -phase, $2H$ -phase, and $2H$ -phase monolayer on top of the bulk $1T$ -phase (hybrid-phase) TaTe₂ have been performed using the density functional theory following the equation 2. Thus, **Figures 2b, 2c, and 2d** are the calculated spectral function intensity plots in the k_x - k_y plane at the Fermi level from the top surface layer of the semi-infinite slabs of $1T$, $2H$, and $2H$ -monolayer placed on top of the semi-infinite $1T$ -TaTe₂ slab (hybrid-phase), respectively. On comparing the experimental Fermi surface with those obtained from the slab calculations, we can find a qualitative agreement between experiment and theory. For instance, the circular-shaped and half-circular-shaped hole pockets are reproduced from the $2H$ -phase. The peanut-shaped hole pocket can be noticed very well from the hybrid-phase, though we can see it from the $1T$ -phase with reduced intensity. Next, the hexagonal-shaped hole pocket is visible only in the hybrid-phase. Nevertheless, the triangular-shaped electron pocket and the petal-shaped hole pockets are not visible from any of these slab calculations, possibly due to their bulk origin.

To elucidate the nature of band dispersions contributing to the Fermi pockets, we plotted in **Figure 3b** the experimentally obtained energy distribution maps (EDMs) taken along ΓK , ΓM , #1, #2, and #3 directions as shown in **Figure 3a**. From these EDMs one can realize that at the Γ point the triangular shaped Fermi sheet has an electronlike band dispersion, while the larger circular- and hexagonal-shaped Fermi sheets have the holelike band dispersions. From the EDM cut #1 we can see that the petal-shaped and half-circle-shaped Fermi sheets have the holelike band dispersions. Similarly, from the EDM cut #2 we

find that the peanut-shaped Fermi sheet at the M point has the holelike band dispersions. Next, the EDM cut #3 identifies holelike band dispersion for the petal-shaped Fermi sheet corresponding to Γ' . Note here that the Fermi vector of the petal-shaped hole pocket is negligible at Γ as it does not cross the Fermi level, however, it has a finite Fermi vector of $0.1\text{\AA}^{-1}$ near the Γ' point. Therefore, the petal-shaped hole pocket has significant k_z dispersion and must be originating from the bulk band structure. Similarly, the triangular-shaped hole pocket at Γ totally disappears at Γ' which is possible only if it is of the bulk nature. Thus, from our experimental data we can unambiguously conclude that the petal-shaped and triangular-shaped Fermi sheets are originated from the bulk bands, while the rest of Fermi sheets are originated from the surface bands. Importantly, overall, the experimental band dispersions are qualitatively in agreement with the calculated band structure of $2H$ (1 ML)/ $1T$ -TaTe₂ as shown in **Figure 3e**. In addition, for a better understanding of the calculated band dispersions, we plotted individual EDMs along the high-symmetry lines of $\overline{\Gamma M}$ and $\overline{\Gamma K}$ from the semi-infinite slab of $1T$ -TaTe₂ (see **Figure 3c**) and $2H$ -TaTe₂ (see **Figure 3d**). Thus, from **Figure 3d** it is clearly evident that the experimental band dispersion noticed at the M point (see **Figure 3b**) is originated from the $2H$ phase.

Figure 4 shows out-of-plane (k_z) ARPES measurements on TaTe₂. **Figure 4a** shows k_z Fermi surface map in $k_{\parallel}$ - k_z plane measured with photon energy ranging from 52 to 100 eV with a step of 3 eV. High symmetry points Γ and A are located on the k_z map. **Figure 4b** depicts the photon energy dependent momentum distribution curves (MDCs). From **Figure 4b** we can notice mainly three peaks, out of which two peaks (shown by the vertical-dashed lines) always present irrespective of the applied photon energy while the middle-peak appears significantly at the photon energies of 66 and 94 eV and then the peak intensity gradually decreases as we move away from these photon energies to totally disappear at photon energies of 52 and 80 eV. **Figure 4c** shows EDM taken along the Γ - A direction. From **Figure 4c** we can notice that the band is crossing the Fermi level near Γ . Observation of the experimental k_z dispersions along the Γ - A high symmetry line are in very good agreement

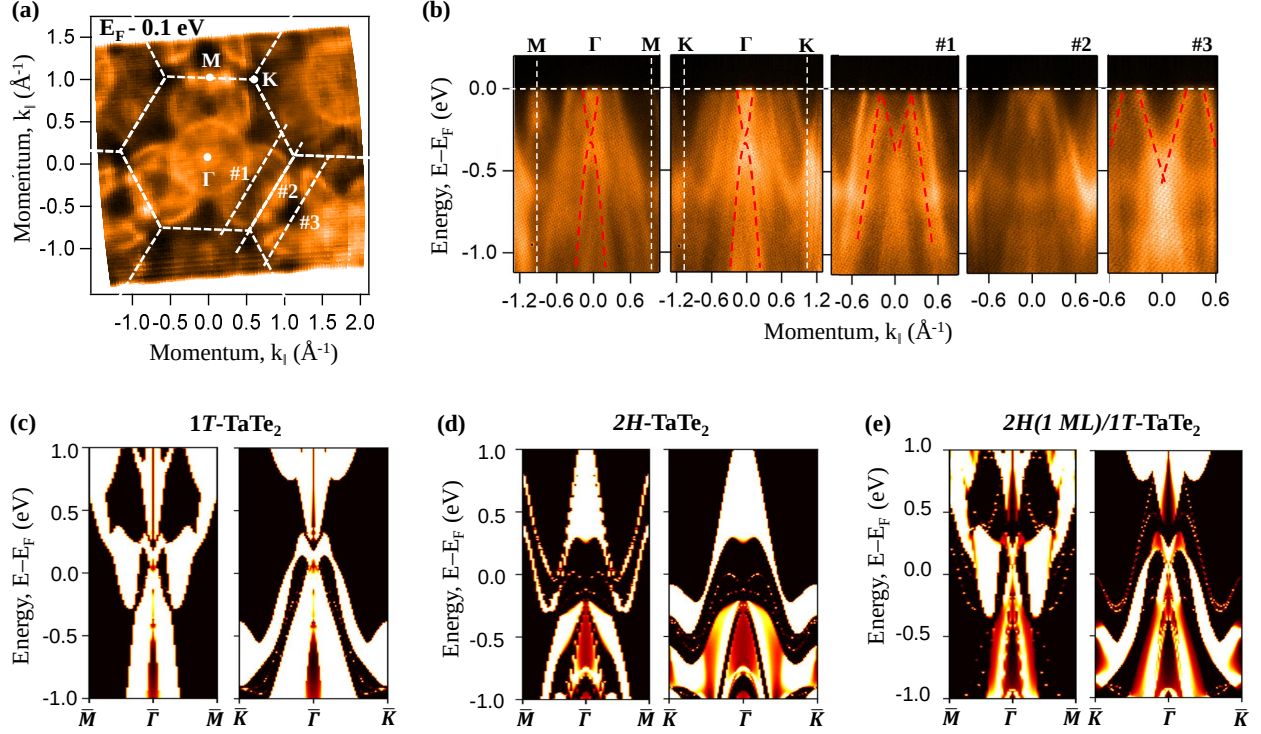


Figure 3: (a) Constant energy contour map taken at binding energy of 0.1 eV below E_F measured with a photon energy $h\nu = 100 \text{ eV}$ (b) Energy distribution maps (EDMs) taken along Γ - K , Γ - M , and along the cuts #1-#3 as shown in (a). (c), (d), and (e) are the calculated energy distribution maps along the high-symmetry lines of $\bar{\Gamma}\bar{M}$ and $\bar{\Gamma}\bar{K}$ plotted for the semi-infinite slabs of 1T, 2H, and 2H-monolayer placed on top of the semi-infinite 1T-TaTe₂ slab, respectively.

with the bulk band structure calculations of 1T-TaTe₂ (see **Figure S3** in the supplemental).

Figure 4d shows energy distribution curves (EDCs) extracted from the EDM shown in

Figure 4c. EDMs along Γ - K and A - H orientation are shown in **Figure 4e**. Following the

equation $k_z = \sqrt{\frac{2m}{\hbar^2}(V_0 + E_k \cos^2 \theta)}$ and considering the inner potential $V_0 = 11 \pm 2 \text{ eV}$ with a lattice constant $c = 9.30$ of low temperature,¹⁸ we identified that the Γ point can be probed with photon energies $h\nu = 66$ and 92 eV , while the A point can be probed with photon energies 54 and 80 eV . Here, m is the rest mass of electron, $\hbar$ is the Planck's constant, E_k is the photoelectron kinetic energy, and θ is photoelectron emission angle with respect to the sample surface normal.

Since TaTe₂ shows CDW order at 170 K ,¹¹ we have measured the ARPES data above and

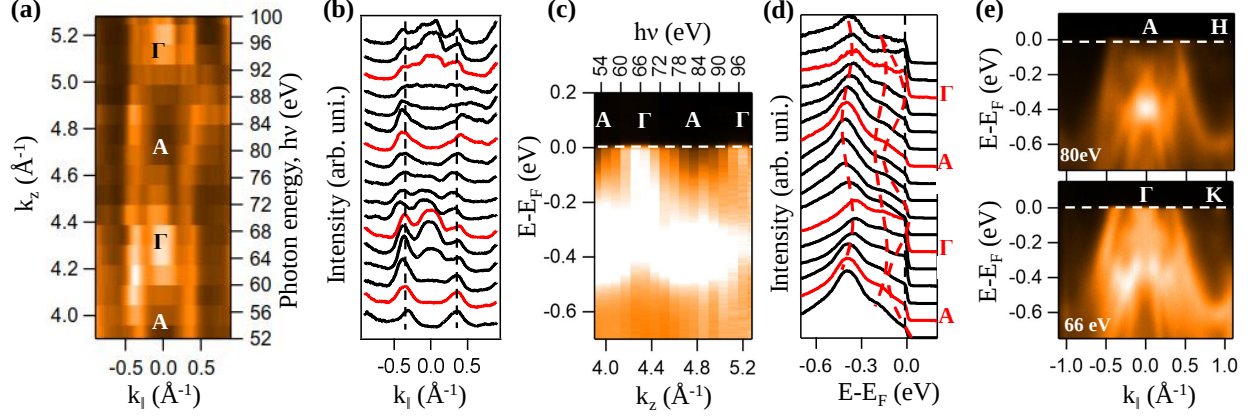


Figure 4: Out-of-plane (k_z) electronic structure of TaTe₂ measured at 1K. (a) k_z Fermi surface map in $\Gamma K H A$ plane. (b) Photon energy dependent momentum distribution curves extracted from (a). (c) Energy distribution map (EDM) taken along the Γ -A high symmetry line. (d) Photon energy dependent energy distribution curves extracted from (c). (e) EDMs taken from Γ -K and A-H high symmetry lines.

below the CDW transition temperature to understand the effect of electronic band structure on the CDW order. **Figure 5** shows the Fermi surface (FS) maps measured with 100 eV photon energy using p polarized light. Left panel in **Figure 5** shows the FS map measured at a sample temperature of 20 K, middle panel is the FS map measured at 180 K, and right panel is the FS map measured at 20 K immediately after cooling down from 180 K. As can be noticed from **Figure 5**, the FS topology hardly changes across the CDW transition temperature, except that over a full temperature cycle the spectral intensity reduced for the surface states (see right panel) due to sample aging.

Next, we compare the experimental band structure of TaTe₂ with the existing literature on the isovalent compounds like, 1T-TaS₂, 1T-TaSe₂ and the isostructural compound 1T'-

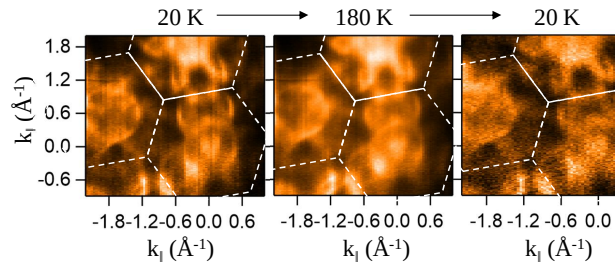


Figure 5: Temperature dependent Fermi surface (FS) topology of TaTe₂. FS measured at 20 K (left), 180 K (middle), and 20 K after cooling down from 180 K (right).

NbTe₂. Despite being the FS topology of these compounds in the hexagonal symmetry we do not find any qualitative agreement with TaTe₂. We identify one circular-shaped and one hexagonal-shaped hole pockets at the Γ point from TaTe₂, whereas no such circular-shaped hole pockets have been found from 1*T*-TaS₂,³⁸ 1*T*-TaSe₂,^{39,40} and 1*T'*-NbTe₂.²² However, the petal-shaped hole pocket noticed in 1*T'*-TaTe₂ is consistent with these systems. Further, the electronic band dispersions of TaTe₂ do neither agree with TaSe₂ nor with TaS₂ which are formed by the isovalent substitution of Se/S at the Te site. This is rare to find drastic changes in the electronic structure by isovalently replacing the chalcogen atom in the TMDCs. It is known that a relative shifting of the valance and conduction bands with isovalent substitution takes place.⁹ Hence, understanding the electronic structure of TaTe₂ has become very complex by simply comparing with the 1*T*-phase of the other similar systems. Importantly, we notice from the total energy calculation of slab 1*T*-TaTe₂ (20 monolayers) that the top surface layer of 1*T*-TaTe₂ favourably transforms into the 2*H*-phase. Moreover, the calculated spectral function of the stand alone 2*H* phase monolayer and the 2*H* phase surface monolayer on top of the semi-infinite 1*T*- phase slab, matches quite well with our ARPES data. In addition, our ARPES data qualitatively agree with the ARPES data of 2*H*-TaSe₂^{41,42} and 2*H*-TaS₂⁴³ where one can find the circular-shaped, half-circular-shaped, and hexagonal-shaped hole pockets at the Γ point. Therefore, the surface states observed on top of the bulk 1*T'*-TaTe₂ from our studies are originated by the surface reconstruction to form 2*H*-TaTe₂.

Finally, we notice that the band structure of TaTe₂ hardly changes across the CDW transition temperature ($T_{CDW} \approx 170$ K) as shown in **Figure 5**, thus, ruling out the Fermi surface nesting mechanism as the origin of CDW ordering in this system. Perhaps, the electron-phonon scattering could be the reason for CDW phase in TaTe₂ as discussed in the previous reports.^{16,22} Also, it is worth to mention here that the 2*H*-phase surface layer is stable even after raising the sample temperature up to 180 K and moving to back 20 K as the Fermi surface topology does not change much with the temperature. An earlier

quantum oscillations study on TaTe₂ suggested the presence of topological Dirac cone in this system.²⁵ But from our systematic ARPES measurements and DFT calculations, we do not observe any signature of the suggested Dirac cone. On the other hand, some of the transport studies on TaTe₂ reported it to be a semimetal.^{25,44,45} Our experimental studies qualitatively support this argument, if we ignore the large number of surface states, as we observe a bulk triangular-shaped electron pocket at the Γ point and six petal-shaped hole pockets surrounding it.

Conclusions

In conclusion, we have systematically studied the low-energy electronic structure of layered Tantalum ditelluride ($1T'$ -TaTe₂) using angle-resolved photoemission spectroscopy and density functional theory. We find that the Fermi surface topology of TaTe₂ is rather different when compared to the isovalant compounds of TaTe₂ such as TaS₂, TaSe₂, and isostructural compound like NbTe₂. Interestingly, we realize that the surface electronic structure of $1T'$ -TaTe₂ has more resemblance to the $2H$ -TaTe₂, while the bulk electronic structure $1T'$ -TaTe₂ has more resemblance to the $1T$ -TaTe₂. These experimental observations are systematically compared with our DFT calculations performed on $1T$ -, $2H$ - and $2H$ (monolayer)/ $1T$ -TaTe₂. We further notice that the Fermi surface topology is temperature independent up to 180 K, confirming that $2H$ phase on the top layer is very stable and the CDW order is not due to the Fermi surface nesting.

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Conflicts of Interest

The authors declare no conflicts of interest.

Supporting Information Available

EDX measurements, additional ARPES data and bulk DFT calculations of TaTe₂ in 1T and 2H phase are shown in the supplemental information.

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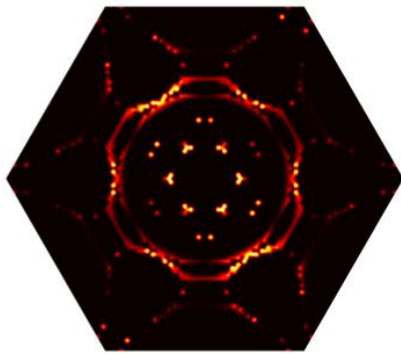
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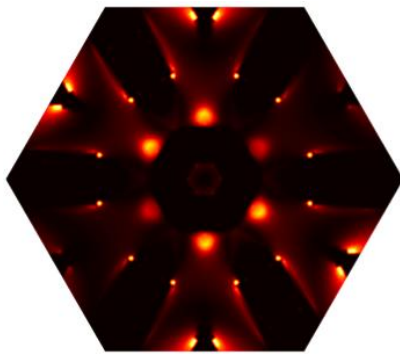
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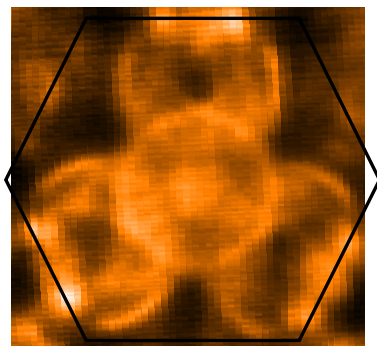
Spectral Function of TaTe₂



DFT: $2H$ -TaTe₂



DFT: $2H/1T$ -TaTe₂



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